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PolarP ${ }^{\text {™ }}$
Power MOSFET

## P-Channel Enhancement Mode Avalanche Rated

TO-263 AA (IXTA)


TO-220AB (IXTP)


| Symbol | Test Conditions | Maximum Ratings |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {DSs }}$ | $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | - 500 | V |
| $\mathrm{V}_{\text {DGR }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{GS}}=1 \mathrm{M} \Omega$ | - 500 | V |
| $\mathrm{V}_{\text {GSS }}$ | Continuous | $\pm 20$ | V |
| $\mathrm{V}_{\text {GSM }}$ | Transient | $\pm 30$ | V |
| $I_{\text {D25 }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | - 10 | A |
| $\underline{\mathrm{Im}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$, Pulse Width Limited by $\mathrm{T}_{\mathrm{JM}}$ | - 30 | A |
| $\mathrm{I}_{\mathrm{A}}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | -10 | A |
| $\mathrm{E}_{\text {AS }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 1.5 | J |
| dv/dt | $\mathrm{I}_{\mathrm{S}} \leq \mathrm{I}_{\mathrm{DM}}, \mathrm{V}_{\mathrm{DD}} \leq \mathrm{V}_{\mathrm{DSS}}, \mathrm{T}_{\mathrm{J}} \leq 150^{\circ} \mathrm{C}$ | 10 | V/ns |
| $\mathrm{P}_{\mathrm{D}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 300 | W |
| $\mathrm{T}_{\mathrm{J}}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {Jм }}$ |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | 1.6 mm (0.062 in.) from Case for 10s | 300 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {sold }}$ | Plastic Body for 10s | 260 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{M}_{\mathrm{d}}$ | Mounting Torque (TO-3P,TO-220 \& TO-247) | 1.13/10 | Nm/lb.in |
| Weight | TO-263 | 2.5 | g |
|  | TO-220 | 3.0 | g |
|  | TO-3P | 5.5 | g |
|  | TO-247 | 6.0 | g |


$V_{\text {DSs }}=-500 \mathrm{~V}$
$I_{\text {D25 }}=-10 \mathrm{~A}$
$R_{\text {DS(on) }} \leq 1 \Omega$

TO-3P (IXTQ)


TO-247 (IXTH)


G = Gate D = Drain
S = Source Tab = Drain

## Features

- International Standard Packages
- Avalanche Rated
- Rugged PolarP ${ }^{\text {TM }}$ Process
- Low Package Inductance
- Fast Intrinsic Diode


## Advantages

- Easy to Mount
- Space Savings
- High Power Density


## Applications

- High-Side Switches
- Push Pull Amplifiers
- DC Choppers
- Automatic Test Equipment
- Current Regulators

| Symbol Test Conditions$\left(T_{j}=25^{\circ} \mathrm{C}\right.$, Unless Otherwise Specified) |  | Characteristic Values |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Typ. | Max. |
| $\mathrm{g}_{\text {fs }}$ | $\mathrm{V}_{\mathrm{DS}}=-10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=0.5 \cdot \mathrm{I}_{\mathrm{D} 25}$, Note 1 | 6.5 | 11 | S |
| $\begin{aligned} & \hline \mathrm{C}_{\text {iss }} \\ & \mathrm{C}_{\text {oss }} \\ & \mathrm{C}_{\mathrm{rss}} \end{aligned}$ | \} $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=-25 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | $\begin{array}{r} 2840 \\ 275 \\ 42 \end{array}$ | pF pF pF |
| $\begin{aligned} & t_{d(o n)} \\ & t_{r} \\ & t_{d(\text { off })} \\ & t_{f} \\ & \hline \end{aligned}$ | Resistive Switching Times $\begin{aligned} & V_{G S}=-10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0.5 \cdot \mathrm{~V}_{\mathrm{DSS}}, \mathrm{I}_{\mathrm{D}}=0.5 \cdot \mathrm{I}_{\mathrm{D} 25} \\ & \mathrm{R}_{\mathrm{G}}=3.3 \Omega \text { (External) } \end{aligned}$ |  | 20 28 52 44 | ns ns ns ns |
| $\begin{aligned} & \mathbf{Q}_{\mathrm{g}(o n)} \\ & \mathbf{Q}_{\mathrm{gs}} \\ & \mathbf{Q}_{\mathrm{gd}} \\ & \hline \end{aligned}$ | \} $\mathrm{V}_{\mathrm{GS}}=-10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0.5 \cdot \mathrm{~V}_{\mathrm{DSS}}, \mathrm{I}_{\mathrm{D}}=0.5 \cdot \mathrm{I}_{\mathrm{D} 25}$ |  | $\begin{aligned} & 50 \\ & 17 \\ & 18 \end{aligned}$ | nC nC nC |
| $\begin{aligned} & \mathbf{R}_{\mathrm{thjc}} \\ & \mathbf{R}_{\mathrm{thcs}} \end{aligned}$ | (TO-3P \& TO-247) <br> (TO-220) |  | $\begin{aligned} & 0.25 \\ & 0.50 \end{aligned}$ | $\begin{array}{r} 0.42^{\circ} \mathrm{C} / \mathrm{W} \\ { }^{\circ} \mathrm{C} / \mathrm{W} \\ { }^{\circ} \mathrm{C} / \mathrm{W} \end{array}$ |

## Source-Drain Diode

| $\begin{aligned} & \text { Symbol Test Conditions } \\ & \left(\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \text {, Unless Otherwise Specified }\right) \\ & \hline \end{aligned}$ |  | Characteristic Values |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Typ. | Max |  |
| $\mathrm{I}_{\text {s }}$ | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}$ |  |  | -10 | A |
| $\mathrm{I}_{\text {SM }}$ | Repetitive, Pulse Width Limited by $\mathrm{T}_{\mathrm{JM}}$ |  |  | -40 | A |
| $\mathrm{V}_{\text {sD }}$ | $\mathrm{I}_{\mathrm{F}}=-5 \mathrm{~A}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$, Note 1 |  |  | - 3 | V |
| $\left.\begin{array}{l} \mathbf{t}_{\mathrm{rr}} \\ \mathbf{Q}_{\mathrm{RM}} \\ \mathbf{I}_{\mathrm{RM}} \end{array}\right\}$ | $\begin{aligned} & I_{F}=-5 A,-d i / d t=-100 A / \mu s \\ & V_{R}=-100 V, V_{G S}=0 V \end{aligned}$ |  | $\begin{array}{r} 414 \\ 5.90 \\ -28.6 \end{array}$ |  | ns $\mu \mathrm{C}$ A |

Note 1: Pulse test, $\mathrm{t} \leq 300 \mu \mathrm{~s}$, duty cycle, $\mathrm{d} \leq 2 \%$.

Fig. 1. Output Characteristics @ $\mathrm{T}_{\mathrm{J}}=\mathbf{2 5}^{\circ} \mathrm{C}$


Fig. 3. Output Characteristics @ $\mathrm{T}_{\mathbf{J}}=\mathbf{1 2 5}{ }^{\circ} \mathrm{C}$


Fig. 5. R $_{\mathrm{DS}(o n)}$ Normalized to $\mathrm{I}_{\mathrm{D}}=-5 \mathrm{~A}$ Value vs.
Drain Current


Fig. 2. Extended Output Characteristics $@ \mathrm{~T}_{\mathrm{J}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$


Fig. 4. $\mathrm{R}_{\mathrm{DS}(o n)}$ Normalized to $\mathrm{I}_{\mathrm{D}}=-5 \mathrm{~A}$ Value vs. Junction Temperature


Fig. 6. Maximum Drain Current vs.


Fig. 7. Input Admittance


Fig. 9. Forward Voltage Drop of Intrinsic Diode


Fig. 11. Capacitance


Fig. 8. Transconductance


Fig. 10. Gate Charge


Fig. 12. Forward-Bias Safe Operating Area


IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

Fig. 13. Maximum Transient Thermal Impedance


## GIXYS <br> IXTA10P50P IXTQ10P50P IXTP10P50P IXTH10P50P

|  |  |  |  | $\frac{4}{41}$ |
| :---: | :---: | :---: | :---: | :---: |
| SYM | INC |  | MILL | ETERS |
| STM | MIN | MAX | MIN | MAX |
| A | 160 | . 190 | 4.06 | 4.83 |
| A1 | . 080 | . 110 | 2.03 | 2.79 |
| b | . 020 | . 039 | 0.51 | 0.99 |
| b2 | . 045 | . 055 | 1.14 | 1.40 |
| c | . 016 | . 029 | 0.40 | 0.74 |
| c2 | . 045 | . 055 | 1.14 | 1.40 |
| D | . 340 | . 380 | 8.64 | 9.65 |
| D1 | . 315 | . 350 | 8.00 | 8.89 |
| E | . 380 | . 410 | 9.65 | 10.41 |
| E1 | . 245 | . 320 | 6.22 | 8.13 |
| e | . 100 | SC | 2.5 | SC |
| L | . 575 | . 625 | 14.61 | 15.88 |
| L1 | . 090 | . 110 | 2.29 | 2.79 |
| L2 | . 040 | . 055 | 1.02 | 1.40 |
| L3 | . 050 | . 070 | 1.27 | 1.78 |
| L4 | 0 | . 005 | 0 | 0.13 |

TO-220 (IXTP) Outline


| $S Y M$ | INCHES |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
| $A$ | .170 | .190 | 4.32 | 4.83 |
| $b$ | .025 | .040 | 0.64 | 1.02 |
| $b 1$ | .045 | .065 | 1.15 | 1.65 |
| $c$ | .014 | .022 | 0.35 | 0.56 |
| $D$ | .580 | .630 | 14.73 | 16.00 |
| $E$ | .390 | .420 | 9.91 | 10.66 |
| $e$ | .100 | BSC | 2.54 BSC |  |
| $F$ | .045 | .055 | 1.14 | 1.40 |
| $H 1$ | .230 | .270 | 5.85 | 6.85 |
| $J 1$ | .090 | .110 | 2.29 | 2.79 |
| $k$ | 0 | .015 | 0 | 0.38 |
| $L$ | .500 | .550 | 12.70 | 13.97 |
| $L 1$ | .110 | .230 | 2.79 | 5.84 |
| $\varnothing P$ | .139 | .161 | 3.53 | 4.08 |
| $Q$ | .100 | .125 | 2.54 | 3.18 |


| (IXTH) Outline |
| :--- | :--- |

TO-3P (IXTQ) Outline


1 - GATE
2 - DRAIN (COLLECTOR)
3 - SOURCE
3 - SOURCE (EVITTER)


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